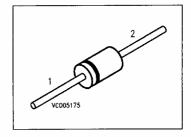
# **SIEMENS**

## **Silicon Variable Capacitance Diodes**

BB 609 A BB 609 B

- Especially for tuning of extended frequency bands in VHF and CATV tuners
- Not for new design



Туре	Marking	Ordering Code	Pin Configuration	Package <sup>1)</sup>
BB 609 A	white	Q62702-B196	1 2	DO-35 DHD
BB 609 B		Q62702-B197	EHA07001	

#### **Maximum Ratings**

Parameter	Symbol	Values	Unit	
Peak reverse voltage	VRM	30	٧	
Forward current, T <sub>A</sub> ≤ 60 °C	IF	20	mA	
Operating temperature range	Top	- 55 + 100	°C	
Storage temperature range	Tstg	- 55 + 150		

## **Electrical Characteristics**

at  $T_A = 25$  °C, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	7
Reverse current $V_R = 30 \text{ V}$ $V_R = 30 \text{ V}$ , $T_A = 60 ^{\circ}\text{C}$	IR			20 200	nA
Diode capacitance, $f = 1$ MHz BB 609 A: $V_R = 1$ V $V_R = 28$ V BB 609 B: $V_R = 1$ V $V_R = 28$ V	Ст	32.5 2.5 33.5 2.8	_ _ _ _	- 3 - 3.2	pF
Capacitance ratio $V_{R} = 1 \text{ V}, 28 \text{ V}; f = 1 \text{ MHz}$	<u>Ст1</u> Ст28	12	-	15	-
Capacitance matching $V_R = 1 \text{ V} \dots 28 \text{ V}, f = 1 \text{ MHz}$	<u>ΔCτ</u> Cτ	-	-	2.5	%
Series resistance $C_T = 12 \text{ pF}, f = 100 \text{ MHz}$	rs	-	0.7	1	Ω
Series inductance	Ls	_	3	-	nH

# Diode capacitance $C_T = f(V_R)$ f = 1 MHz

